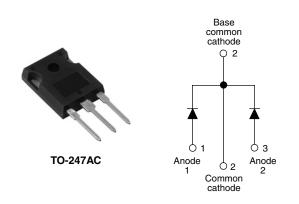
Vishay High Power Products

HEXFRED[®] Ultrafast, Soft Recovery Diode, 2 x 25 A



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PRODUCT SUMMARY				
V _R	600 V			
V _F at 25 A at 25 °C	1.7 V			
I _{F(AV)}	2 x 25 A			
t _{rr} (typical)	23 ns			
T _J (maximum)	150 °C			
Q _{rr} (typical)	112 nC			
dl _{(rec)M} /dt (typical) at 125 °C	160 A/µs			
I _{RRM} (typical)	4.5 A			

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating conditions
- Designed and qualified for industrial level

BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

HFA50PA60C is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A per leg continuous current, the HFA50PA60C is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{BBM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA50PA60C is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		600	V	
Maximum continuous forward currentper leg	- I _F	T _C = 100 °C	25		
per device			50	А	
Single pulse forward current	I _{FSM}		225	A	
Maximum repetitive forward current	I _{FRM}		100		
Maximum power dissipation	P _D	T _C = 25 °C	150	W	
		T _C = 100 °C	60	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

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ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
		I _F = 25 A		-	1.3	1.7	v
Maximum forward voltage	V_{FM}	I _F = 50 A	See fig. 1	-	1.5	2.0	
		I _F = 25 A, T _J = 125 °C		-	1.3	1.7	
Maximum reverse	1	$V_{R} = V_{R}$ rated	See fig. 2	-	1.5	20	
leakage current	I _{RM}	T_J = 125 °C, V_R = 0.8 x V_R rated	See lig. 2	-	600	2000	μΑ
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	55	100	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 12 -		nH			

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time See fig. 5, 10	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	0 Α/μs, V _R = 30 V	-	23	-	ns
	t _{rr1}	T _J = 25 °C		-	50	75	
	t _{rr2}	T _J = 125 °C		-	105	160	
Peak recovery current	I _{RRM1}	T _J = 25 °C	I _F = 25 A dI _F /dt = 200 A/μs V _R = 200 V	-	4.5	10	A nC
See fig. 6	I _{RRM2}	T _J = 125 °C		-	8.0	15	
Reverse recovery charge See fig. 7	Q _{rr1}	T _J = 25 °C		-	112	375	
	Q _{rr2}	T _J = 125 °C		-	420	1200	
Peak rate of fall of recovery current during t _b See fig. 8	dl _{(rec)M} /dt1	T _J = 25 °C		-	250	-	A./
	dl _{(rec)M} /dt2	T _J = 125 °C		-	160	-	A/μs

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Junction to case, single leg conducting	P		-	-	0.83		
Junction to case, both legs conducting	R _{thJC}		-	-	0.42		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	– K/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-		
Waight			-	6.0	-	g	
Weight			-	0.21	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)	
Marking device		Case style TO-247AC	HFA50PA60C				



HEXFRED[®] Vishay High Power Products Ultrafast, Soft Recovery Diode, 2 x 25 A

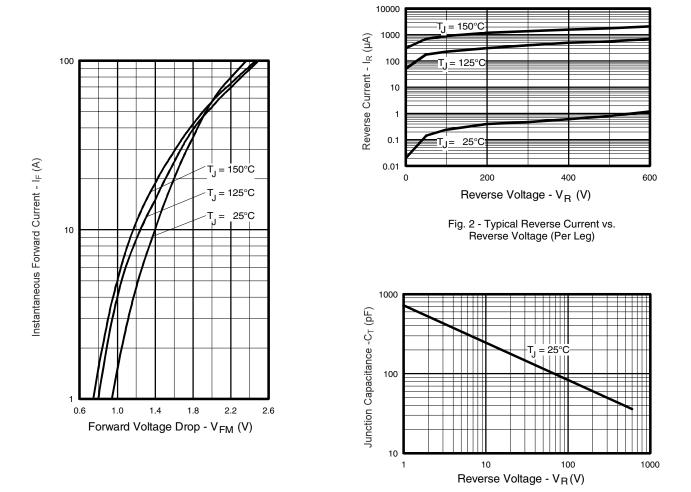
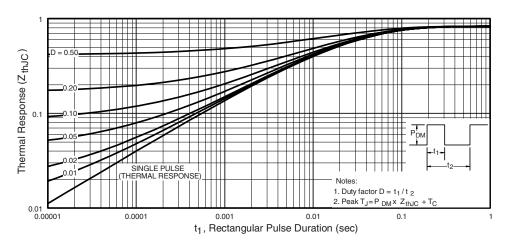


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





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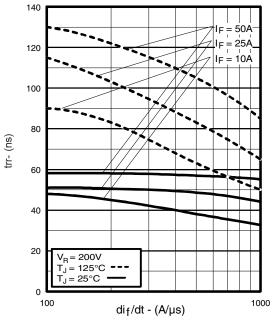
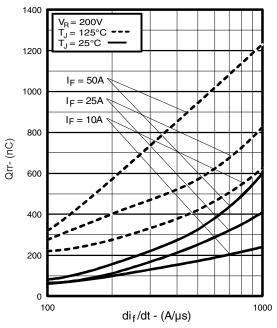


Fig. 5 - Typical Reverse Recovery Time vs. dI_{F}/dt (Per Leg)



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Fig. 7 - Typical Stored Charge vs. dI_F/dt (Per Leg)

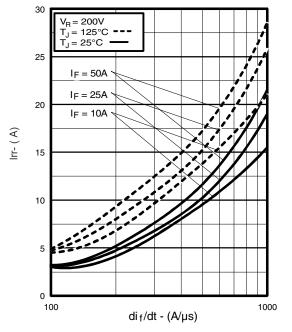


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

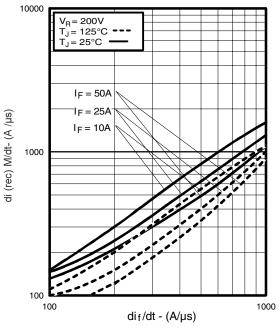


Fig. 8 - Typical $dI_{(rec)M}/dt vs. dI_F/dt$ (Per Leg)





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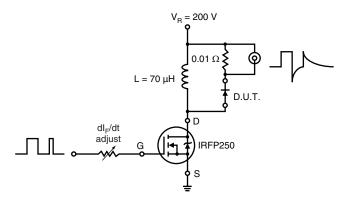


Fig. 9 - Reverse Recovery Parameter Test Circuit

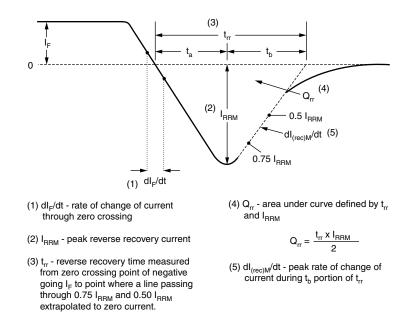


Fig. 10 - Reverse Recovery Waveform and Definitions

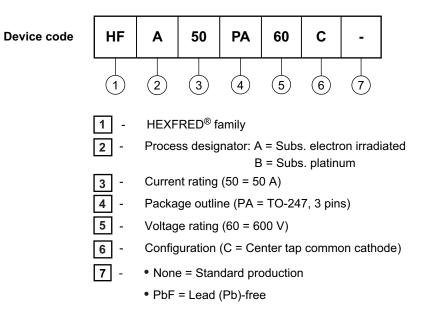
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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95223					
Part marking information	http://www.vishay.com/doc?95226				



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